## FYS3410 - Vår 2010 (Kondenserte fasers fysikk)

http://www.uio.no/studier/emner/matnat/fys/FYS3410/index-eng.xml

Based on Introduction to Solid State Physics by Kittel

#### **Course content**

- Periodic structures, understanding of diffraction experiment and reciprocal lattice
- Crystal binding, elastic strain and waves
- Imperfections in crystals: point defects and diffusion
- Crystal vibrations: phonon heat capacity and thermal conductivity
- Free electron Fermi gas: density of states, Fermi level, and electrical conductivity
- Electrons in periodic potential: energy bands theory classification of metals, semiconductors and insulators
- Semiconductors: band gap, effective masses, charge carrier distributions, doping, pn-junctions
- Metals: Fermi surfaces, temperature dependence of electrical conductivity

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#### FYS3410 lecture schedule and exams: Spring 2010

M/18/1/2010:	Introduction and motivation. Periodicity and lattices	2h
W/20/1/2010:	Index system for crystal planes. Crystal structures	1h
M/25/1/2010:	Reciprocal space, Laue condition and Ewald construction	2h
W/27/1/2010:	Brillouin Zones. Interpretation of a diffraction experiment	1h
M/01/2/2010:	Crystal binding, elastic strain and waves	2h
W/03/2/2010:	Elastic waves in cubic crystals; defects in crystals	1h
M/08/2/2010:	Defects in crystals; case study - vacancies	2h
W/10/2/2010:	Diffusion	1h
M/15/2/2010:	Crystal vibrations and phonons	2h
W/17/2/2010:	Crystal vibrations and phonons	1h
M/22/2/2010:	Lattice heat capacity: Dulong-Petit and Einstein models	2h
W/24/2/2010:	Phonon density of states (DOS) and Debye model	1h
M/01/3/2010:	General result for DOS; role of anharmonic interactions	2h
W/03/3/2010:	Thermal conductivity	1h
M/08/3/2010:	Free electron Fermi gas in 1D and 3D – ground state	2h
W/10/3/2010:	Density of states, effect of temperature – FD distribution	1h
M/15/3/2010:	Heat capacity of FEFG	2h
W/17/3/2010:	Repetition	1h
22/3/2010:	Mid-term exam	

M/14/4/2010:	Electrical and thermal conductivity in metals	2h
W/12/4/2010:	Bragg reflection of electron waves at the boundary of BZ	1h
M/19/4/2010:	Energy bands, Kronig - Penny model	2h
W/21/4/2010:	Empty lattice approximation; number of orbitals in a band	1h
M/26/4/2010:	Semiconductors, effective mass method, intrinsic carriers	2h
W/28/4/2010:	Impurity states in semiconductors and carrier statistics	1h
M/03/5/2010:	p-n junctions and heterojunctions	2h
W/05/5/2010:	surface structure, surface states, Schottky contacts	2h
M/10/5/2010: W/12/5/2010:	no lectures no lectures	
W/19/5/2010:	Repetition	2h
W26/5/2010:	Repetition	2h
27-28/5/2010:	Final Exam (sensor: Prof. Arne Nylandsted Larsen at the Aarhus University Denmark, http://person.au.dk/en/anl@phys.au.dk)	,

• Repetition: Calculating phonon density of states - DOS - in 1-, 2- and 3-dimensions

- Debye model: explaining approximations and derivation of T<sup>3</sup> temperature dependence for heat capacity
- Anharmonic crystal interactions

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#### Calculating phonon density of states – DOS – in 1-D

Since atoms *s* and s+N have the same displacement, we can write:

 $u_s = u_{s+N} \longrightarrow ue^{i(ksa-\omega t)} = ue^{i(k(s+N)a-\omega t)} \longrightarrow 1 = e^{ikNa}$ 

This sets a condition on allowed k values:  $kNa = 2\pi n \rightarrow k = \frac{2\pi n}{Na}$  n = 1, 2, 3, ...

So the separation between allowed solutions (k values) is:  $\Delta k = \frac{2\pi}{Na} \Delta n = \frac{2\pi}{Na}$  independent of k, so the density of modes in k-space is uniform

Thus, in 1-D:  $\frac{\# of \ modes}{interval \ of \ k-space} = \frac{1}{\Delta k} = \frac{Na}{2\pi} = \frac{L}{2\pi}$ 

#### Calculating phonon density of states – DOS – in 3-D

Now for a 3-D lattice we can apply periodic boundary conditions to a sample of  $N_1 \times N_2 \times N_3$  atoms:

 $\frac{\# of \ modes}{volume \ of \ k-space} = \frac{N_1 a}{2\pi} \frac{N_2 b}{2\pi} \frac{N_3 c}{2\pi} = \frac{V}{8\pi^3} = N(k)$ 

Now we know from before that we can write the differential # of modes as:

$$dN = N(\omega)d\omega = N(k)d^{3}\vec{k} = \frac{V}{8\pi^{3}}d^{3}\vec{k}$$

We carry out the integration in k-space by using a "volume" element made up of a constant  $\omega$  surface with thickness dk:

$$d^{3}\vec{k} = (surface \ area) \ dk = \left| \int dS_{\omega} \right| dk$$

#### Calculating phonon density of states – DOS – in 3-D

Rewriting the differential number of modes in an interval:  $dN = N(\omega)d\omega = \frac{V}{8\pi^3}\int dS_{\omega}dk$ 

We get the result:

$$N(\omega) = \frac{V}{8\pi^3} \int dS_{\omega} \frac{dk}{d\omega} = \frac{V}{8\pi^3} \int dS_{\omega} \frac{1}{\frac{\partial \omega}{\partial k}}$$

A very similar result holds for N(E) using constant energy surfaces for the density of electron states in a periodic lattice!

This equation gives the prescription for calculating the density of modes  $N(\omega)$  if we know the dispersion relation  $\omega(k)$ .

We can now set up the Debye's calculation of the heat capacity of a solid.

- Repetition: Calculating phonon density of states DOS in 1-, 2- and 3-dimensions
- Debye model: explaining approximations and derivation of T<sup>3</sup> temperature dependence for heat capacity

Anharmonic crystal interactions

#### **Debye model**

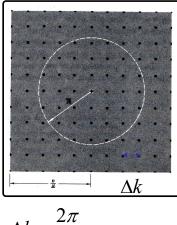
We know that we need to evaluate an upper limit for the heat capacity integral:

$$C_V(T) = \int_{\omega=0}^{\omega_{\max}} N(\omega) C_E(\omega, T) d\omega$$

If the dispersion relation is known, the upper limit will be the maximum  $\omega$  value. But Debye made several simple assumptions, consistent with a uniform, isotropic, elastic solid:

- 3 independent polarizations (L,  $T_1$ ,  $T_2$ ) with <u>equal</u> propagation speeds  $v_g$
- continuous, elastic solid:  $\omega = v_g k$
- $\omega_{max}$  given by the value that gives the correct number of modes per polarization (N)

## Lattice heat capacity: Debye model





 $N_{k} = \left(\frac{L}{2\pi}\right)^{3} \frac{4\pi}{3} k^{3} = \left(\frac{L}{2\pi}\right)^{3} \frac{4\pi\omega^{3}}{3v^{3}} = \frac{V\omega^{3}}{6\pi^{2}v^{3}}$  $D(\omega) = \frac{dN_k}{d\omega} = \frac{V\omega^2}{2\pi^2 v^3}$  Density of states of acoustic phonos for 1 polarization  $\omega(k) = vk$  phonon dispersion relation Debye temperature  $\theta$  $N = \frac{V\omega_D^3}{6\pi^2 v^3} \implies \frac{\hbar\omega_D = k_B \theta}{\theta = \frac{\hbar v}{k_B} \left(\frac{6\pi^2 N}{V}\right)^{\frac{1}{3}}}$ 

 $N_k$ : Allowed number of k points in a sphere with a radius k

*N*: number of unit cell

Thermal energy U and lattice heat capacity  $C_V$ : Debye model

3 polarizations for acoustic modes

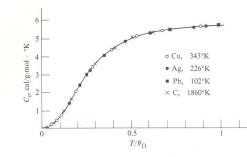
$$U = 3\int d\omega D(\omega)n(\omega)\hbar\omega = 3\int_{0}^{\omega_{D}} d\omega \frac{V\omega^{2}}{2\pi^{2}v^{3}} \frac{\hbar\omega}{\exp(\hbar\omega/k_{B}T) - 1}$$
$$C_{V} = \left(\frac{\partial U}{\partial T}\right)_{V} = \frac{3V\hbar^{2}}{2\pi^{2}v^{3}k_{B}T^{2}}\int_{0}^{\omega_{D}} d\omega \frac{\omega^{4}\exp(\hbar\omega/k_{B}T)}{\left[\exp(\hbar\omega/k_{B}T) - 1\right]^{2}}$$
$$C_{V} = 9Nk_{B}\left(\frac{T}{\theta}\right)^{3}\int_{0}^{x_{D}} dx \frac{x^{4}e^{x}}{(e^{x} - 1)^{2}}$$

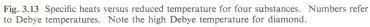
## **Debye model**

Better agreement than Einstein model at low T

Universal behavior for all solids!

Debye temperature is related to "stiffness" of solid, as expected



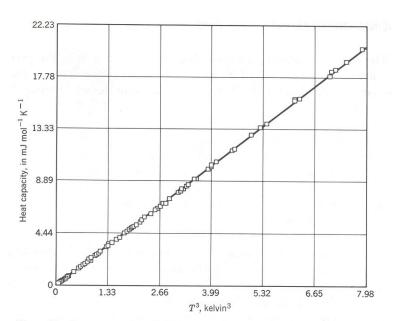


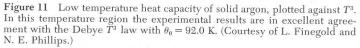
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Element	$\theta_{\rm D}$ , °K	Compound	$\theta_{\rm D}, {}^{\circ}{\rm K}$
Li	335	NaCl	280
Na	156	KC1	230
K	91.1	CaF <sub>2</sub>	470
Cu	343	LiF	680
Ag	226	$SiO_2$ (quartz)	255
Au	162		
Al	428		
Ga	325		
Pb	102		
Ge	378		
Si	647		
С	1860		

#### **Debye model**

Quite impressive agreement with predicted  $C_V \propto T^3$ dependence for Ar! (noble gas solid)





- Repetition: Calculating phonon density of states DOS in 1-, 2- and 3-dimensions
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## I Anharmonic Properties of Solids

Two important physical properties that ONLY occur because of anharmonicity in the potential energy function:

- 1. Thermal expansion
- 2. Thermal resistivity (or <u>finite</u> thermal conductivity)

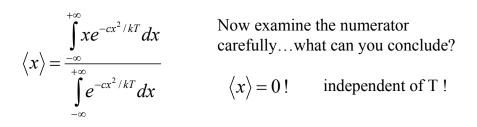
#### Thermal expansion

In a 1-D lattice where each atom experiences the same potential energy function U(x), we can calculate the average displacement of an atom from its T=0 equilibrium position:

$$\langle x \rangle = \frac{\int\limits_{-\infty}^{+\infty} x e^{-U(x)/kT} dx}{\int\limits_{-\infty}^{+\infty} e^{-U(x)/kT} dx}$$

# Thermal Expansion in 1-D

Evaluating this for the harmonic potential energy function  $U(x) = cx^2$  gives:



Thus any nonzero  $\langle x \rangle$  must come from terms in U(x) that go beyond x<sup>2</sup>. For HW you will evaluate the approximate value of  $\langle x \rangle$  for the model function

$$U(x) = cx^2 - gx^3 - fx^4$$
 (c, g,  $f > 0$  and  $gx^3$ ,  $fx^4 << kT$ )

Why this form? On the next slide you can see that this function is a reasonable model for the kind of U(r) we have discussed for molecules and solids.

